



A Product Line of Diodes Incorporated



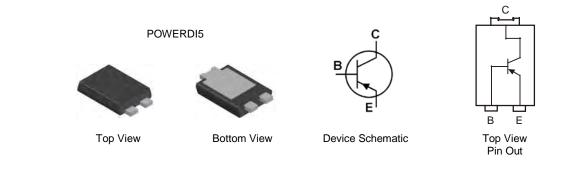
#### 40V PNP HIGH GAIN TRANSISTOR POWERDI<sup>®</sup>

#### Features

- BV<sub>CEO</sub> > -40V
- $I_C = -3A$  high Continuous Collector Current
- I<sub>CM</sub> = -6A Peak Pulse Current
- 43% smaller than SOT223; 60% smaller than TO252
- Maximum Height Just 1.1mm
- Rated up to 3.2W
- Low Saturation, High Gain Transistor,
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe.
  Solderable per MIL-STD-202, Method 208 3
- Weight: 0.093 grams (approximate)



### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT790AP5-13	DXT790A	13	16	5,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## **Marking Information**



DXT790A = Product Type Marking Code )'' = Manufacturers' Code Marking K = Factory Designator YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 09 for 2009) WW = Week code (01 to 53)





### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Continuous Collector Current	lc	-3	А
Peak Pulse Current	I <sub>CM</sub>	-6	А
Base Current	IB	-0.5	А

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.2		
Power Dissipation	(Note 6)	PD	1.7	W	
	(Note 7)		0.74		
	(Note 5)		39		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R <sub>θ</sub> JA	75	°C/W	
	(Note 7)	Ť	169		
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ ext{ heta}JL}$	8.9	°C/W	
Operating and Storage Temperature Range		TJ, T <sub>STG</sub>	-55 to +150	٥°C	

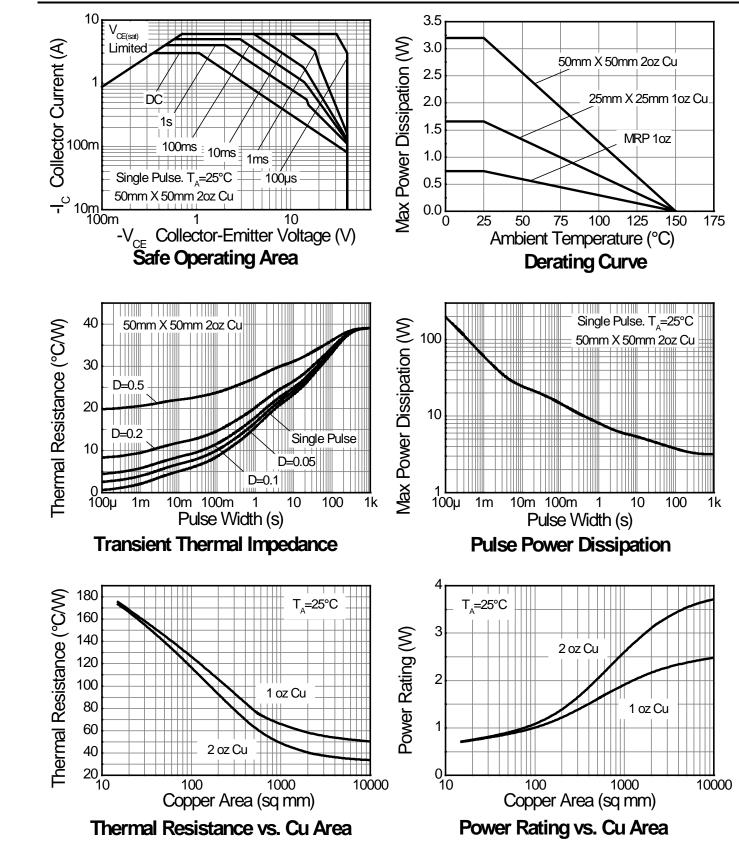
 For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
 Same as note (5), except the device is mounted on minimum recommended pad (MRP) layout 1oz copper.
 The result paint is the except the device is mounted on the result of the result Notes:

8. Thermal resistance from junction to solder-point (on the exposed collector pad).





## Thermal Characteristics and Derating Information



POWERDI is a registered trademark of Diodes Incorporated. DXT790AP5 Document number: DS31800 Rev. 3 - 2





**DXT790AP5** 

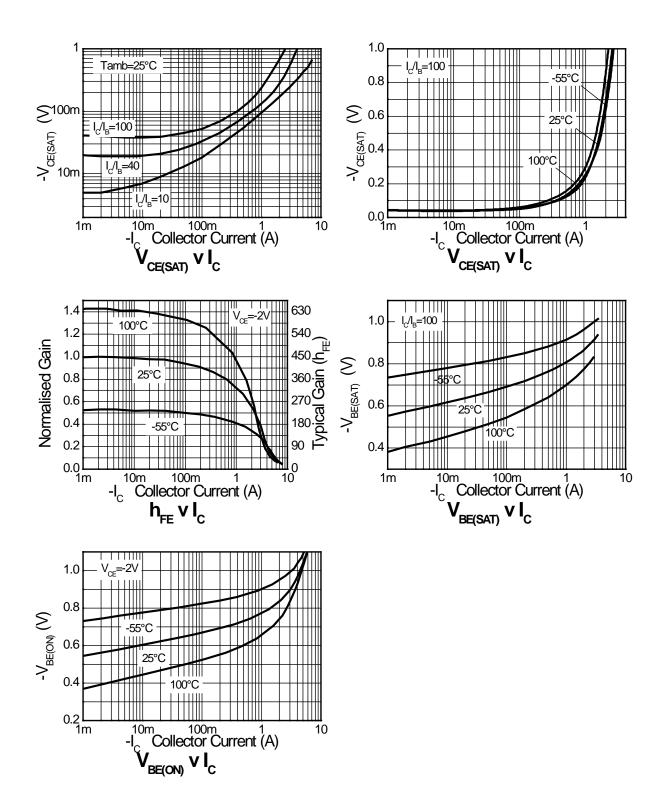
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

				n		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						-
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50			V	$I_{\rm C} = -100 \mu {\rm A}, \ I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-40			V	$I_{C} = -10 \text{mA}, I_{B} = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	—		V	$I_E = -100 \mu A$ , $I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	—	-20	nA	$V_{CB} = -30V, I_E = 0$
Collector Cutoff Current	ICES	_	—	-20	nA	$V_{CB} = -30V, V_{BE} = 0$
Emitter Cutoff Current	I <sub>EBO</sub>	_		-20	nA	$V_{EB} = -4V, I_{C} = 0$
ON CHARACTERISTICS (Note 8)	•					
		_	_	-170		I <sub>C</sub> = -0.5A, I <sub>B</sub> = -5mA
Collector-Emitter Saturation Voltage	V	_	—	-350	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -10mA
Collector-Emiller Saturation Voltage	V <sub>CE(sat)</sub>	—	—	-450	IIIV	$I_{C} = -2A, I_{B} = -50mA$
			—	-450		$I_{C} = -3A, I_{B} = -300mA$
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	—	-1.15	V	$I_{C} = -3A, I_{B} = -300mA$
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	_	—	-1.0	V	$I_{C} = -3A, V_{CE} = -2V$
		300	_	800		$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$
		250	_	_		$I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain	h <sub>FE</sub>	200	_	—	_	$I_{C} = -1A, V_{CE} = -2V$
		150	—	—		$I_{C} = -2A, V_{CE} = -2V$
		80	—	—		$I_{C} = -3A, V_{CE} = -2V$
AC CHARACTERISTICS						
Transition Frequency	f <sub>T</sub>	100	_	_	MHz	$I_C = -50$ mA, $V_{CE} = -5V$ , f = 50MHz
Output Capacitance	Cobo		24		pF	$V_{CB} = -10V, f = 1MHz$
Switching Times	t <sub>on</sub>	_	35		ns	I <sub>C</sub> = -500mA, V <sub>CC</sub> = -10V,
Switching Times	t <sub>off</sub>	_	600	—	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$

8. Measured under pulsed conditions. Pulse width• 300µs. Duty cycle• 2%. Notes:



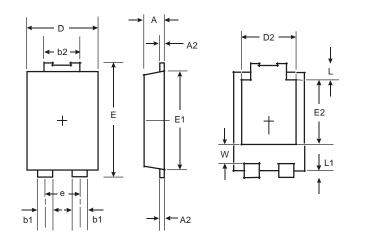
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# Package Outline Dimensions

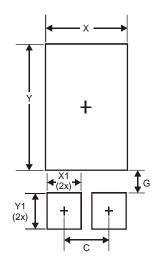
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI5				
Dim	Min	Max		
Α	1.05	1.15		
A2	0.33	0.43		
b1	0.80	0.99		
b2	1.70	1.88		
D	3.90	4.05		
D2	3.054 Typ			
Е	6.40	6.60		
е	1.84 Typ			
E1	5.30	5.45		
E2	3.549 Typ			
L	0.75	0.95		
L1	0.50	0.65		
w	1.10	1.41		
All Di	All Dimensions in mm			

### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Y	4.860
Y1	1.400



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